R&S 2022 低軌道衛星與無線通訊線上研討會



C-K Clive Tzuang, professor emeritus, National Taiwan University; life fellow, IEEE

15:50-16:20 January 24, 2022

dedicate this presentation to **professor** 陳哲俊



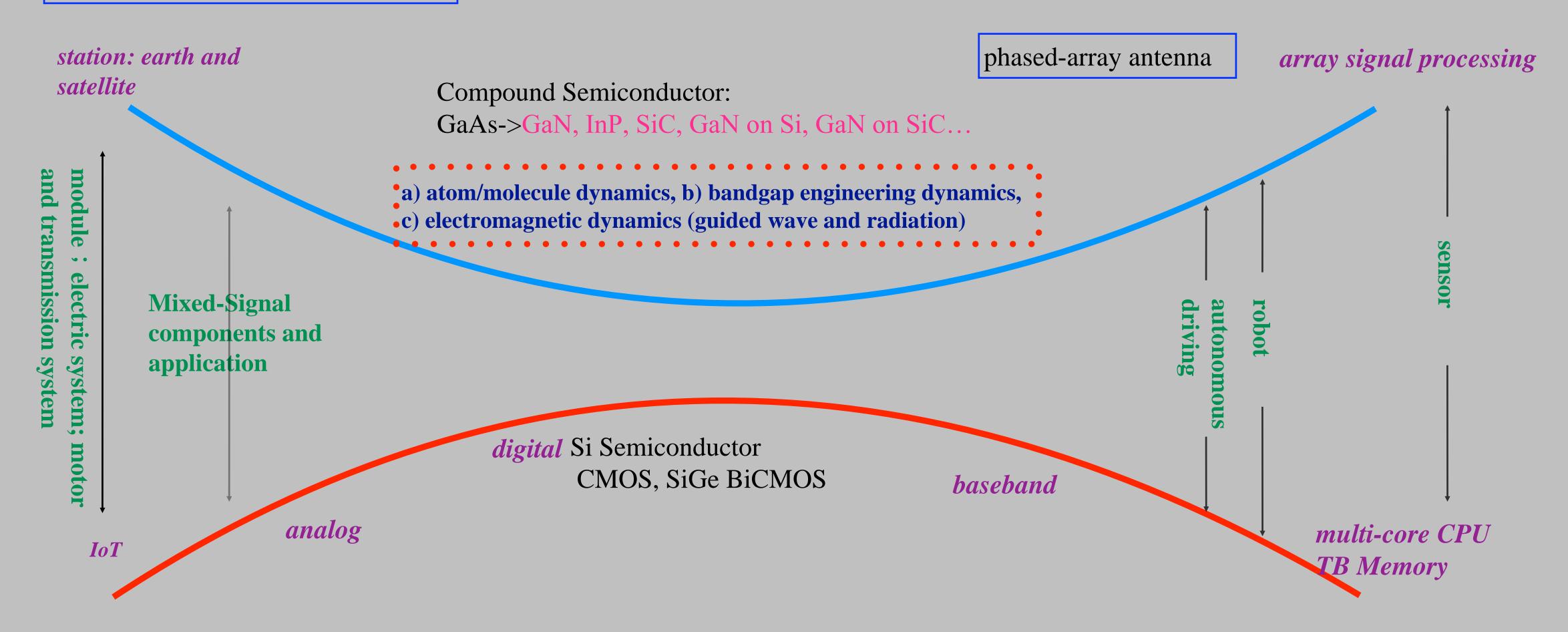
Caption

on behalf of IEEE Taipei Life Member Affinity Group (LMAG) Join IEEE

congratulate all attendees on opportunity working on Taiwan space technology

(quasi-optical) imaging

high-power components and system

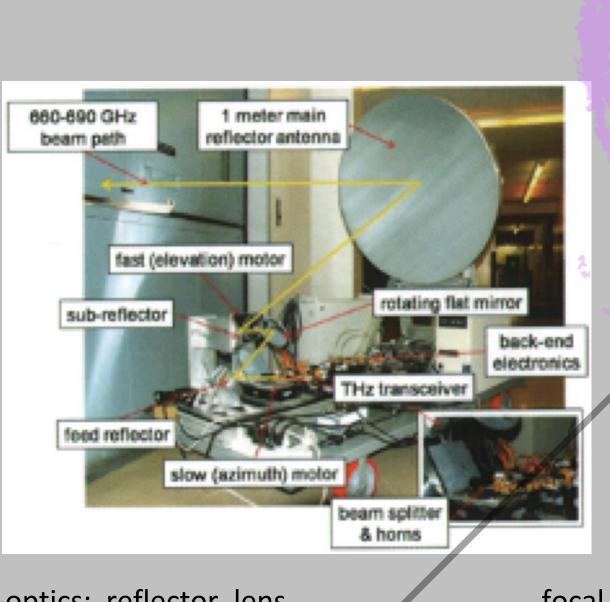


array integration _system perspective

heat

all digital

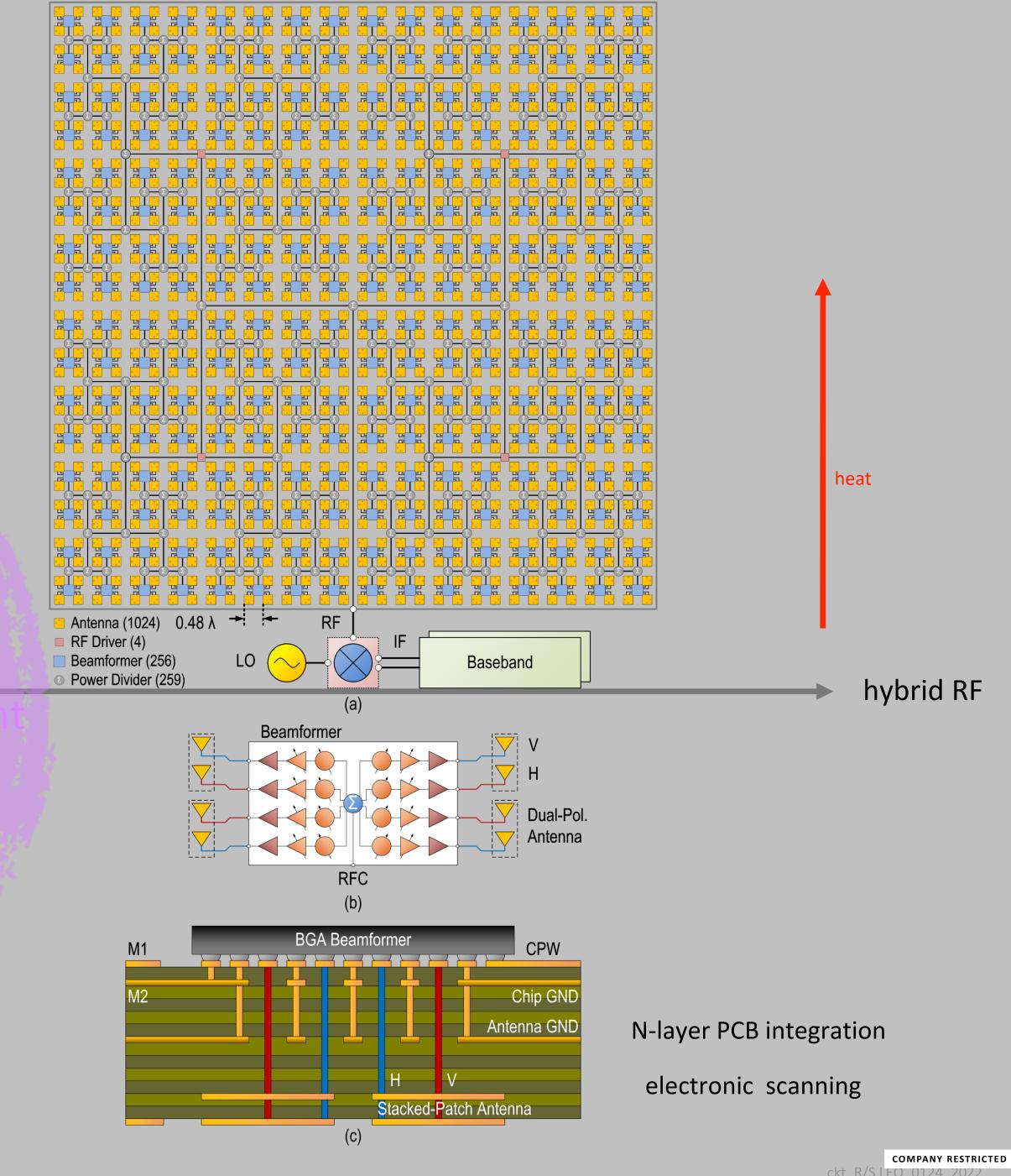
N-layer PCB integration electronic scanning



quasi-optics: reflector, lens

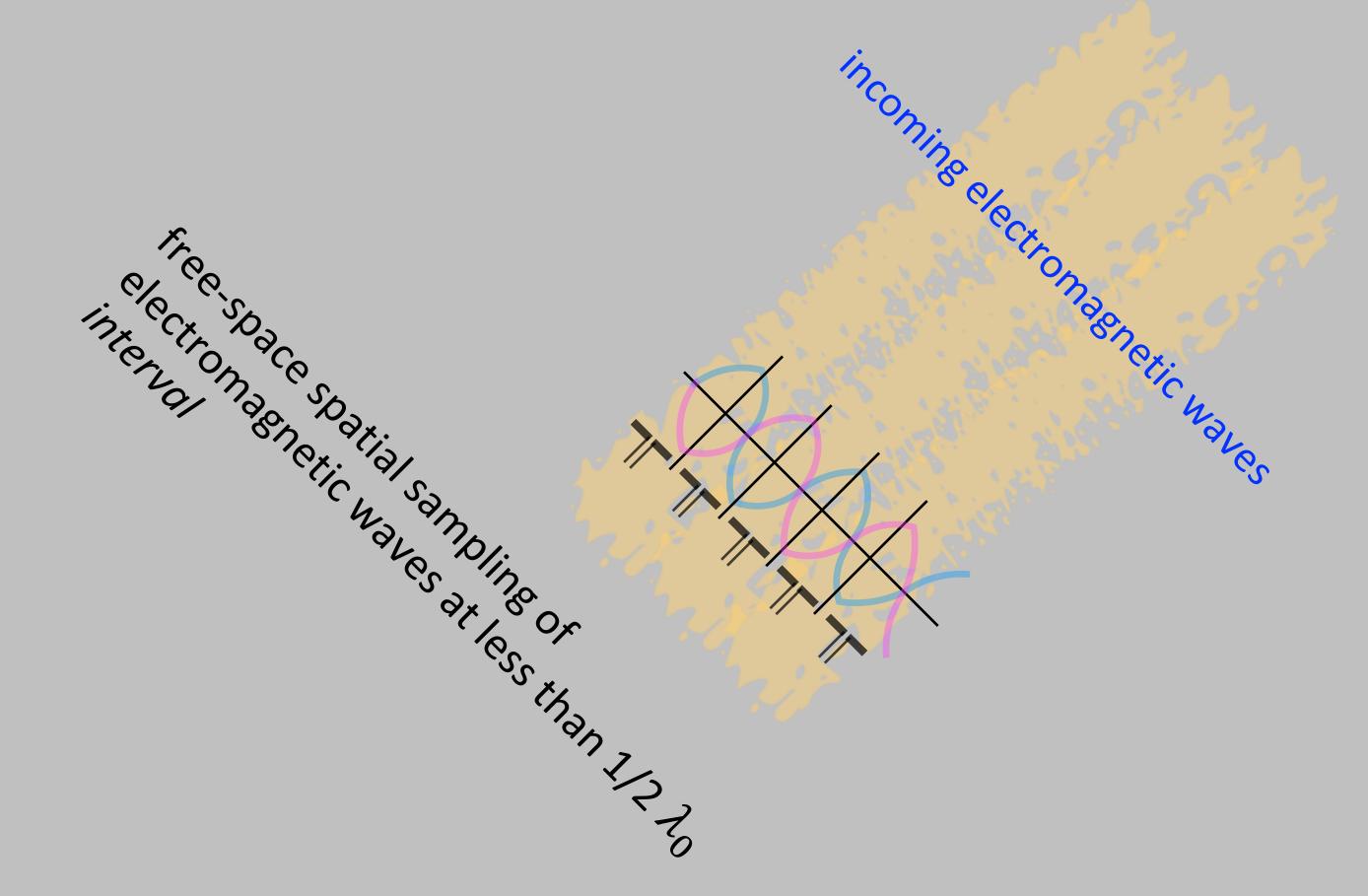
lens

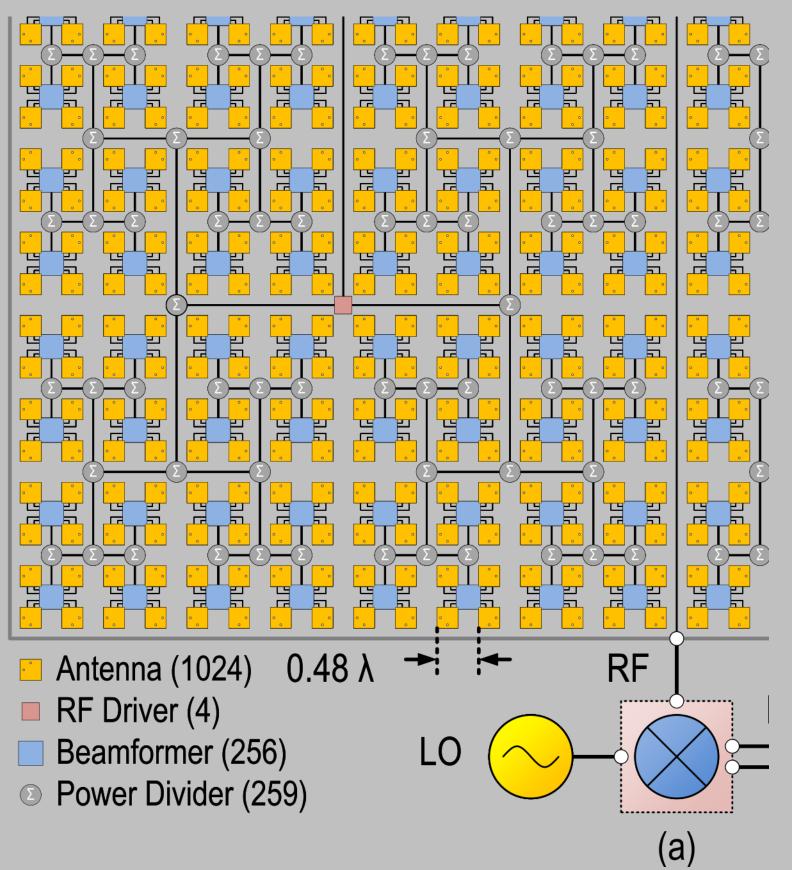
focal plane array M-layer Si MEMS integration mechanical scanning



array integration _limit, risk, opportunity

1. Shannon Sampling Theorem





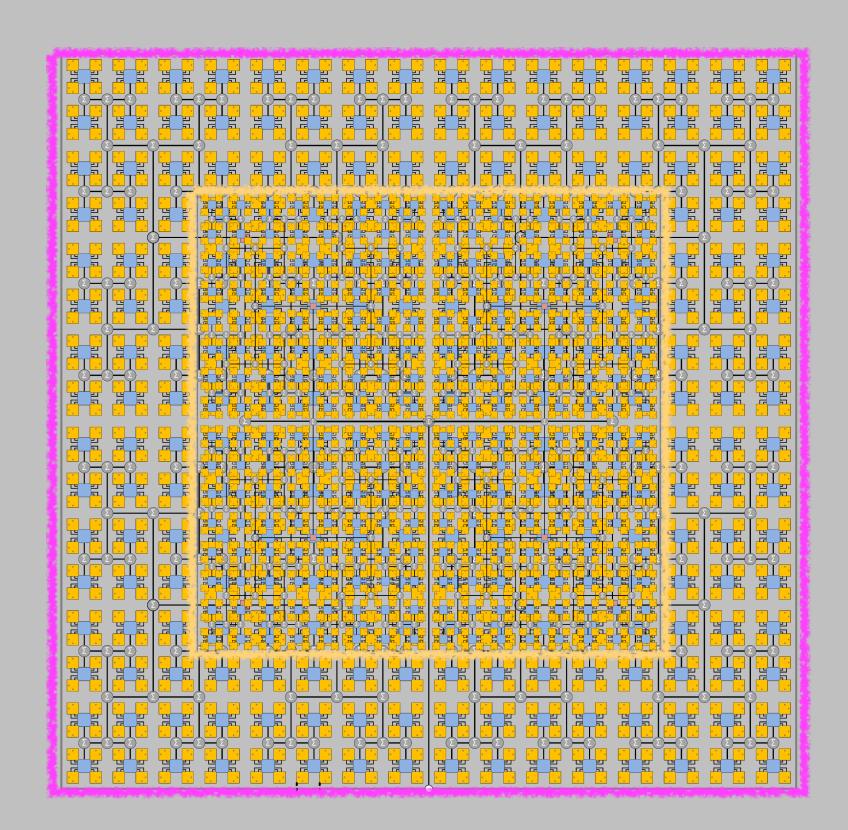
2. RF package or chip dimension (PA as an example)

Part #	\$	Description	Frequency Min \$ GHz	Frequency Max \$ GHz	Pout ‡ dBm	Psat ‡ dBm	Gain ‡ dB	PAE	OIP3	Voltage √	Current \$ mA	Package Type \$	Package
19 Matching Product (91 total) ADD/REMOVE PARAM	_	Reset All	37.5 ————————————————————————————————————	42.5	28	35	36.5 16, S21	> 15	47	-2.8 to 28	2,500 40 for final	CP Cu Base Die Flange Laminate overmold Overmold QFN OVM QFN	1.8 x 1.8 x 0.10 11.4 x 17.3 x 3 15.2 x 15.2 x 3.5 15.24 x 15.24 x 3.5 2.4 x 1.8 x 0.10
Compare Parametric	Filters ^										stage carrier		
□ QPA2211D	PDF	27.5 - 31 GHz, 14 Watt GaN Amplifier	27.5	31	41.5		17	34		22	280	Die	2.740 x 2.552 x 0.050
☐ QPA2211T	PDF	27.5 - 31 GHz 14 Watt GaN Power Amplifier	27.5	31	41.5								
☐ QPA2212D	PDF	27.5 - 31 GHz, 25 Watt GaN Power Amplifier	27.5	31		43.4							
☐ QPA2212T	PDF	27.5 - 31 GHz 25 Watt GaN Power Amplifier	27.5	31		43.4							
☐ QPA2226D	PDF	34 - 36 GHz 20 Watt GaN Amplifier	34	36	43								
☐ QPA2229D	PDF	34 - 36 GHz, 13 Watt GaN Amplifier	34	36	41.2	41.2		15		28	50	Die	3.29 x 2.60 x 0.05
☐ QPA2640D	PDF	20 - 40 GHz 8 Watt GaN Amplifier	20	40		39				18	2,040	Die	5.87 x 3.50 x 0.05
QPA4246D NEW	PDF	37.5 - 42.5 GHz 10 Watt GaN Amplifier	37.5	42.5		40	16, S21	17		24	270	Die	4.2 x 5.0 x 0.5
QPA4346D NEW	PDF	37.5 - 42.5 GHz 6 Watt GaN Amplifier	37.5	42.5		38	16, S21	20		24	140	Die	4.2 x 2.5 x 0.5
QPA4446D NEW	PDF	37.5 - 42.5 GHz 4 Watt GaN Amplifier	37.5	42.5		36	18, S21	25		24	70	Die	3.26 x 1.49 x 0.5
☐ TGA2222	PDF	32 - 38 GHz 10 Watt GaN Amplifier	32	38	40	40	16	22		26			3.43 x 2.65 x 0.05
☐ TGA4548	PDF	17 - 20 GHz 10 Watt GaN Power Amplifier	17	20	40		27	30		28	300		
☐ TGA4548-SM	PDF	17 - 20 GHz 10 Watt GaN Power Amplifier	17	20	40		27	25		28	300		5.0 x 5.5 x 1.7
TO A SEAD OM		24.2 22.6 CH= 40 Wett CoN Dower	24.2	22.6	40		25	20			200		EOVEE V

3. Bi-static to Monostatic

Rx

Tx



Bi-static

Monostatic

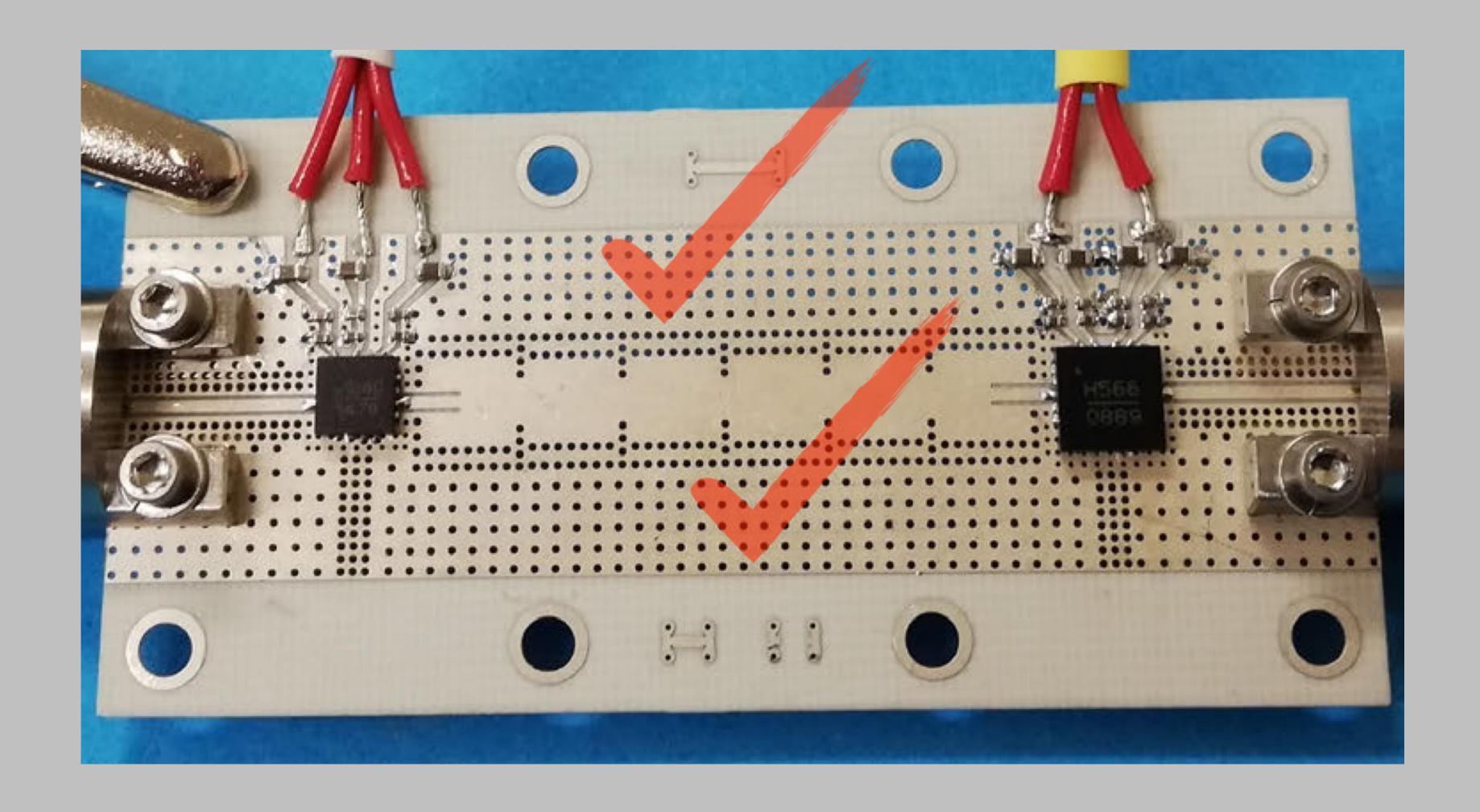
4. Heat Generation (only PA considered here)

All PAs in the table are valid for a satellite RF TX 1024-element array implementation, and we set EiRP of 66 dBm with zero ohmic loss; thus each antenna (6 dBi gain) radiates 1 Watt to account for total of radiated power at 1024 W.

At 30 % PAE, seemingly an impressive number from the table, implies the amount of approximately 2,389 Watts (1024 W/(1-0.7)) x 0.7) dissipated into heat, not mentioning losses stemming from interconnections and passive components, poor matching, drivers, LNAs, etc, really hot for the small area of $16 \lambda_0$ by $16 \lambda_0$.

5. Avoid excite undesirable modes

example: a Ka band receiver for inner satellite link: a LNA with an image-rejection filter



Conclusion

6. How to test thousands of RF components on board at every development stage?

Welcome aboard in pursuit of satellite communication system technology; it is immensely interesting, multi-disciplinary, multi-physics, and funs to meet challenges.

Road is narrow, gate is small, however.

Yet, the most precious moment for Formosans to enter frontier satellite business.